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<u>PATENT</u> 22307Z-132800US Docket No.:

Attorney Docket No.: 02307Z-132800US Client Reference No.: 2003-145-1

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

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TOWNSEND and TOWNSEND and CREW LLP

By: ハッリン

Mark T. Davis

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Julin Wan, Amiya K. Mukherjee, and Matthew J. Gasch

Application No.: 10/773,758

Filed: February 6, 2004

For: NANOCOMPOSITES OF SILICON NITRIDE, SILICON CARBIDE, AND

**BORON NITRIDE** 

Examiner: Not Yet Assigned

Art Unit: 1755

INFORMATION DISCLOSURE

STATEMENT UNDER 37 CFR §1.97 and

§1.98

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The references cited on attached form PTO/SB/08B are being called to the attention of the Examiner. Copies of the non-U.S. references are enclosed. In accordance with the USPTO waiver of the requirement under 37 CFR 1.98 (a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. patent application publication for all U.S. patent applications filed after June 30, 2003, applicant has not submitted copies of the U.S. references.

As provided for by 37 CFR 1.97(g) and (h), no inference should be made that the information and references cited are prior art merely because they are in this statement and no representation is being made that a search has been conducted or that this statement encompasses all the possible relevant information.

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Julin Wan, Amiya K. Mukherjee, and Matthew J.

Application No.: 10/773,758

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Applicant believes that <u>no fee is required</u> for submission of this statement.

However, if a fee is required, the Commissioner is authorized to deduct such fee from the undersigned's Deposit Account No. 20-1430. Please deduct any additional fees from, or credit any overpayment to, the above-noted Deposit Account.

Respectfully submitted,

M. Henry Heines

Reg. No. 28,219

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MHH:mtd 60217872 v1

Substitute for form 1449 SPTO Complete if Known Application Number 10/773,758 INFORMATION DISC Filing Date February 6, 2004 STATEMENT BY APPLICANT Wan, Julin First Named Inventor Art Unit 1755 (use as many sheets as necessary) Examiner Name Not Yet Assigned of Attorney Docket Number 02307Z-132800US Sheet

U.S. PATENT DOCUMENTS+						
		Document Number				
Examiner Initials*	Cite No.1	Number Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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Signature	 Considered	

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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INFORMATION DISCLOSURE
STATEMENT BY APPLICANT

Complete if Known

Application Number 10/773,758

Filing Date February 6, 2004

First Named Inventor Wan, Julin

Art Unit 1755

Examiner Name Not Yet Assigned

Attomey Docket Number 02307Z-132800US

(use as many sheets as necessary)

Sheet 4 of

				FOREIGN PA	TENT DOCUME	NTS		
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Name of Patentee or	Pages, Columns, Line Where Relevant		
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>s</sup> (if known)	Publication Date MM-DD-YYYY	Applicant of Cited  Document	Passages or Relev Figures Appear	ant _
			NO	N PATENT LIT	ERATURE DOC	UMENTS		
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.						
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<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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